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BFL4036

N-Channel Power MOSFET 500V, 14A, 0.52Ω, TO-220F-3FS

Features

- ON-resistance $R_{DS(on)}=0.4\Omega$ (typ.)
- Input capacitance $C_{iss}=1000\text{pF}$ (typ.)
- 10V drive

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	V_{DS}		500	V
Gate to Source Voltage	V_{GS}		± 30	V
Drain Current (DC)	I_{DC}^{*1}	Limited only by maximum temperature $T_{ch}=150^\circ\text{C}$	14	A
	I_{Dpack}^{*2}	$T_c=25^\circ\text{C}$ (Our ideal heat dissipation condition)*3	9.6	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	50	A
Allowable Power Dissipation	P_D		2.0	W
		$T_c=25^\circ\text{C}$ (Our ideal heat dissipation condition)*3	37	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$
Avalanche Energy (Single Pulse) *4	E_{AS}		109	mJ
Avalanche Current *5	I_{AV}		14	A

Note : *1 Shows chip capability

*2 Package limited

*3 Our condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

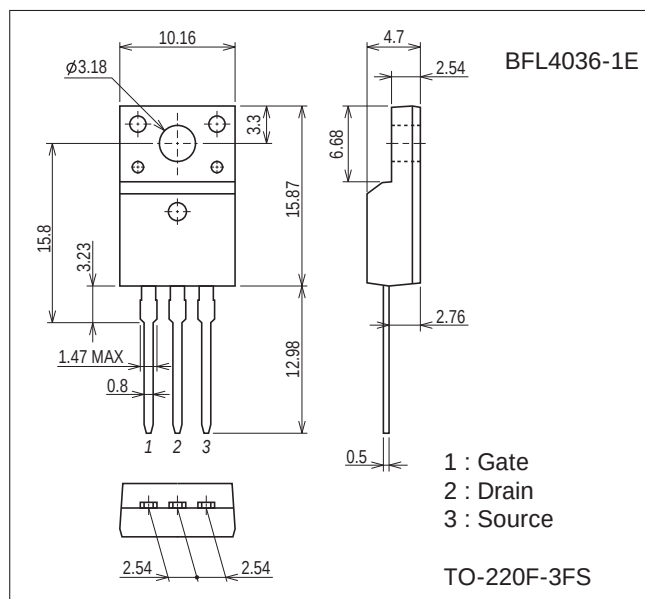
*4 $V_{DD}=50\text{V}$, $L=1\text{mH}$, $I_{AV}=14\text{A}$ (Fig.1)*5 $L \leq 1\text{mH}$, single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Package Dimensions

unit : mm (typ)

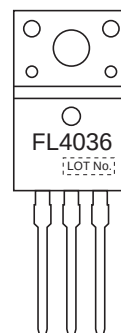
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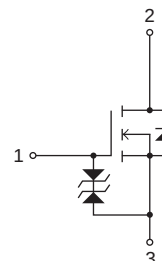
Ordering & Package Information

Device	Package	Shipping	memo
BFL4036-1E	TO-220F-3FS SC-67	50 pcs./tube	Pb-Free

Marking



Electrical Connection



Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=10mA, V_{GS}=0V$	500			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=400V, V_{GS}=0V$			100	μA
Gate to Source Leakage Current	I_{GSS}	$V_{GS}=\pm 24V, V_{DS}=0V$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	3		5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=7A$	3.5	7		S
Static Drain to Source On-State Resistance	$R_{DS(on)}$	$I_D=7A, V_{GS}=10V$		0.4	0.52	Ω
Input Capacitance	C_{iss}	$V_{DS}=30V, f=1MHz$		1000		pF
Output Capacitance	C_{oss}			200		pF
Reverse Transfer Capacitance	C_{rss}			44		pF
Turn-ON Delay Time	$t_{d(on)}$	See Fig.2		22		ns
Rise Time	t_r			66		ns
Turn-OFF Delay Time	$t_{d(off)}$			117		ns
Fall Time	t_f			46		ns
Total Gate Charge	Q_g	$V_{DS}=200V, V_{GS}=10V, I_D=14A$		38.4		nC
Gate to Source Charge	Q_{gs}			6.7		nC
Gate to Drain "Miller" Charge	Q_{gd}			22.1		nC
Diode Forward Voltage	V_{SD}	$I_S=14A, V_{GS}=0V$		0.95	1.3	V
Reverse Recovery Time	t_{rr}	See Fig.3		520		ns
Reverse Recovery Charge	Q_{rr}			4200		nC

Fig.1 Unclamped Inductive Switching Test Circuit

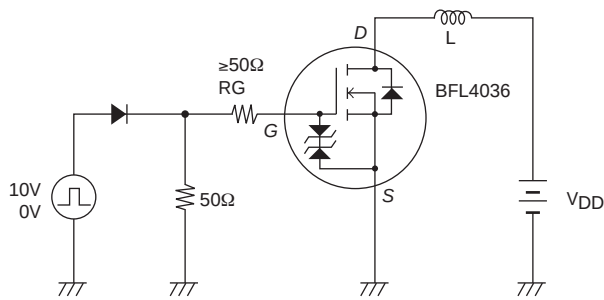


Fig.2 Switching Time Test Circuit

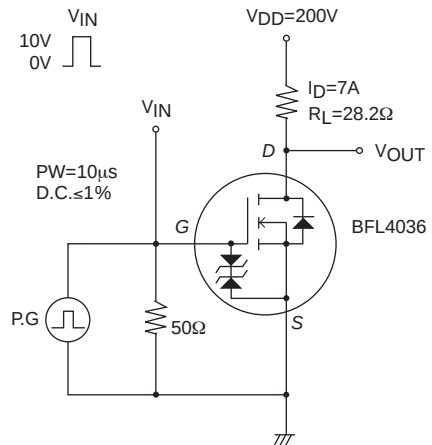
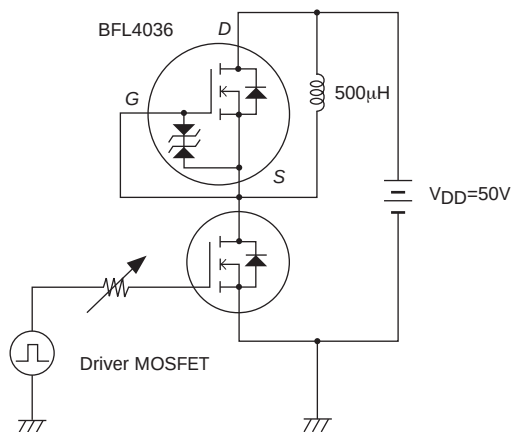
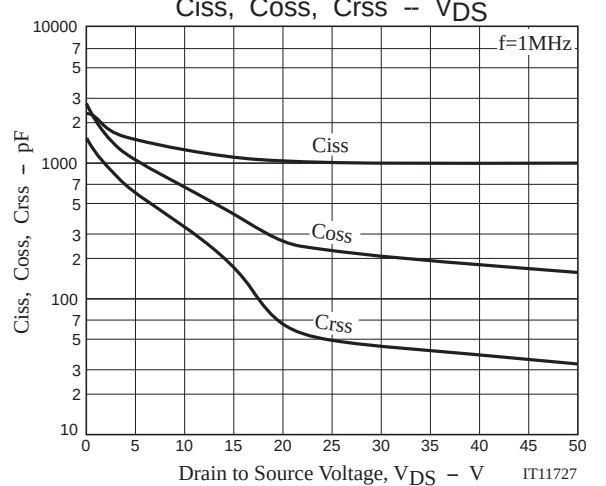
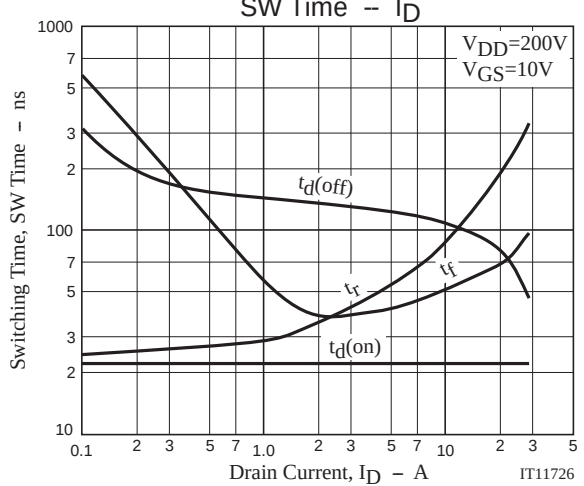
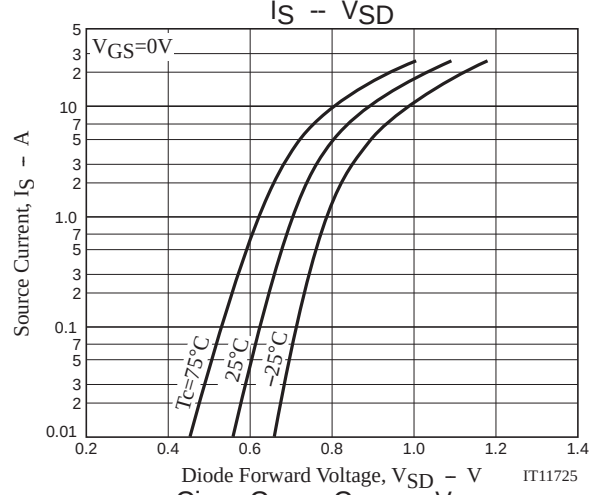
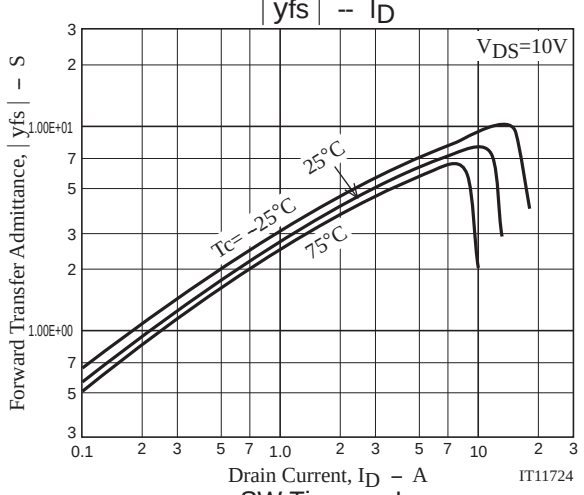
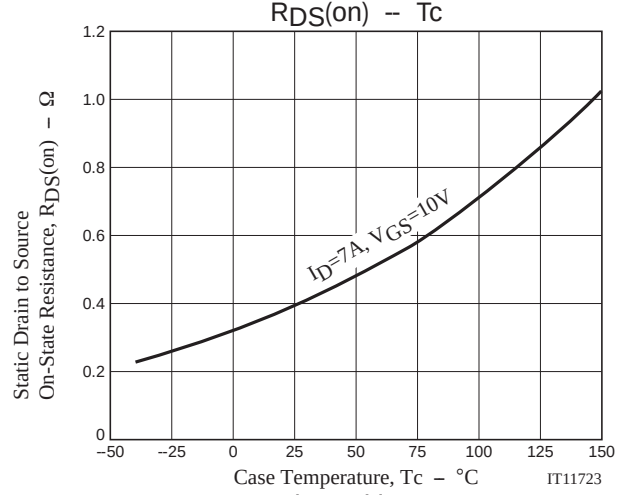
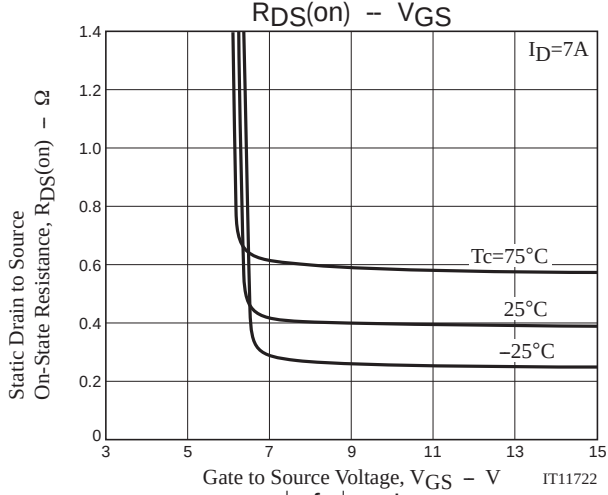
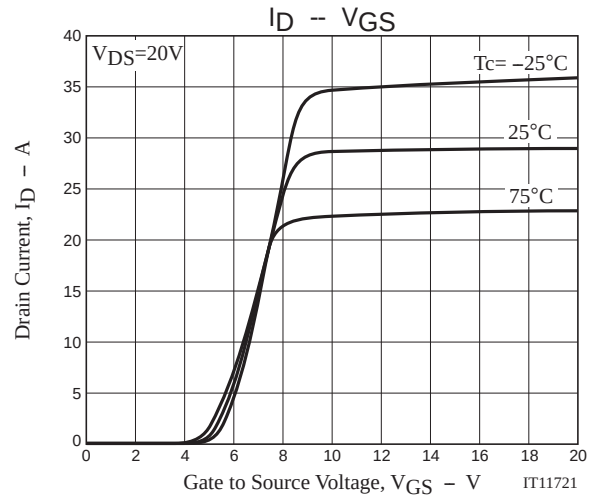
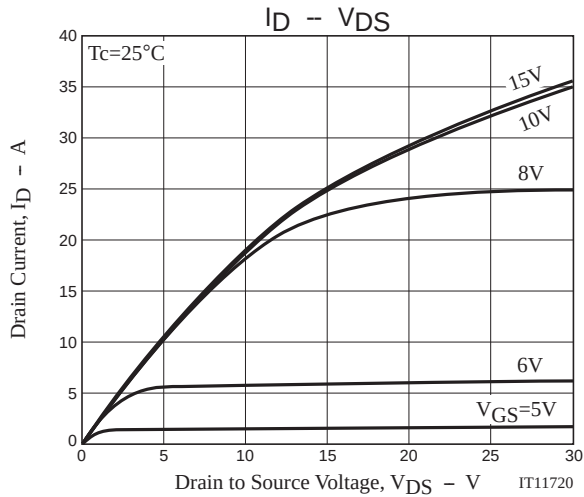
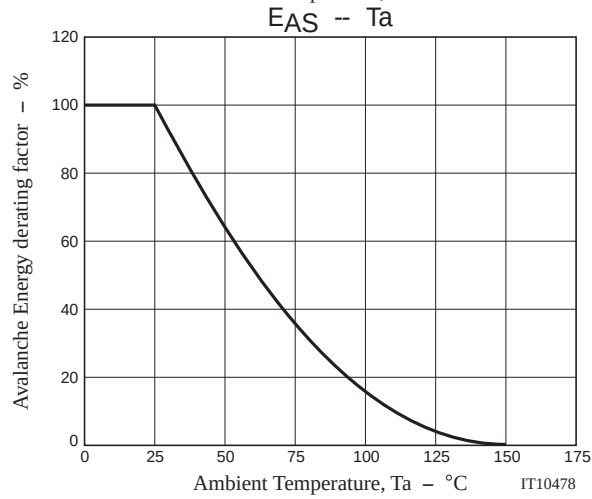
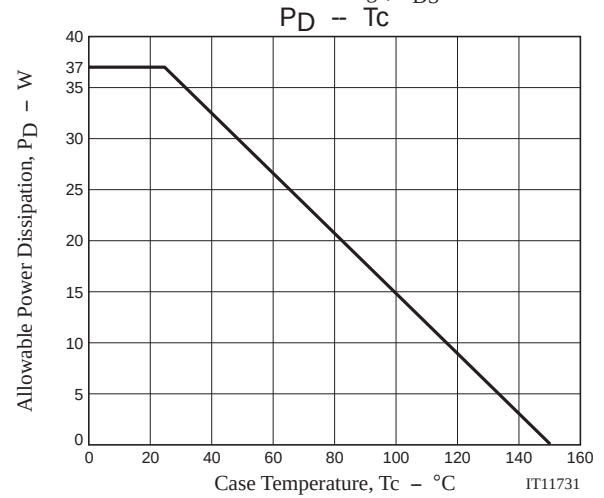
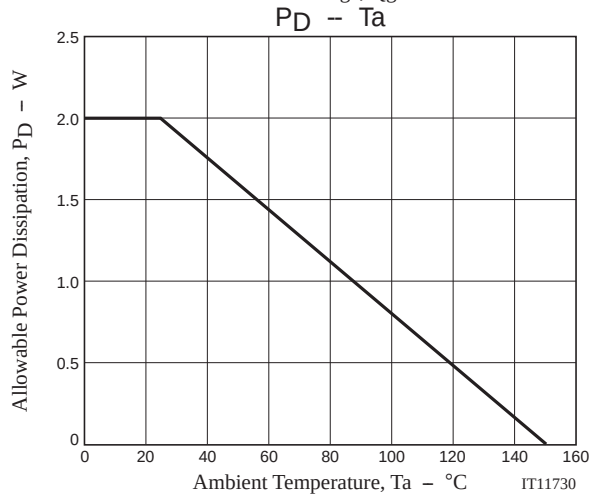
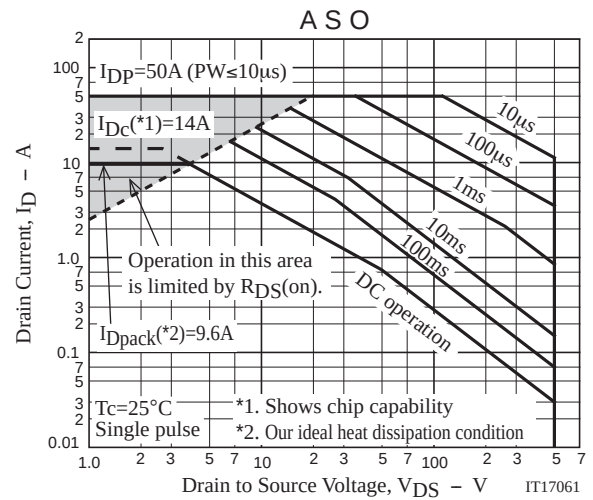
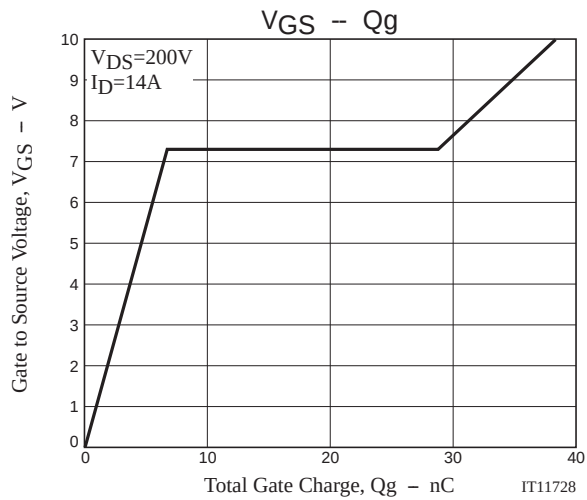


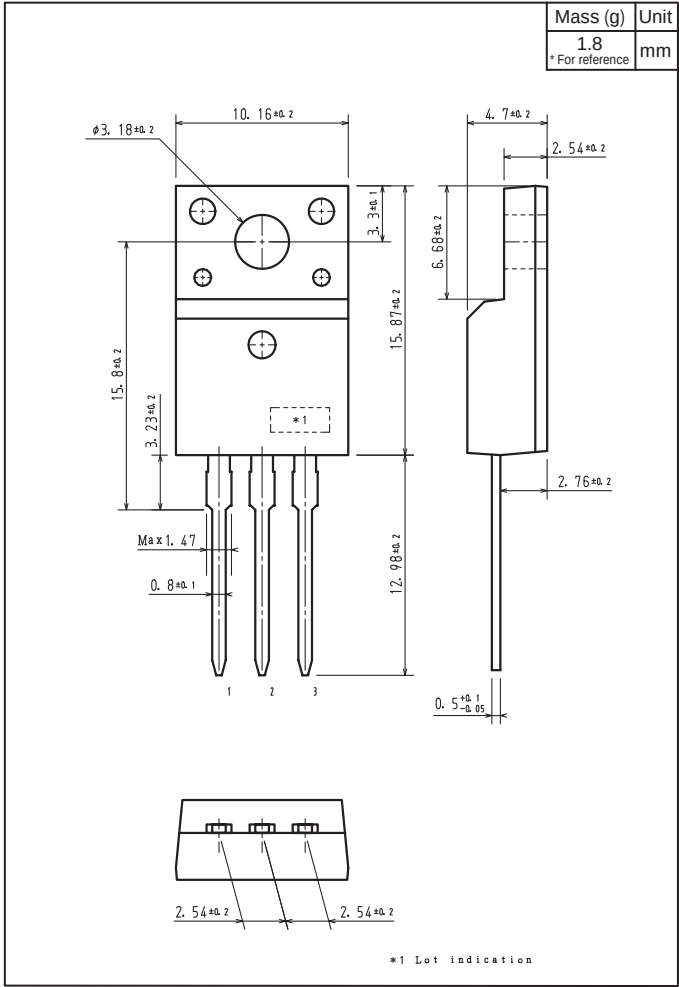
Fig.3 Reverse Recovery Time Test Circuit







Outline Drawing
BFL4036-1E



Note on usage : Since the BFL4036 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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